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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I²C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, Cap Sense, DMA, I²S, LCD, POR, PWM, WDT
Number of I/O	83
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	10K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l152v8t6

3.1 Low power modes

The ultra-low-power STM32L151x6/8/B and STM32L152x6/8/B devices support dynamic voltage scaling to optimize its power consumption in run mode. The voltage from the internal low-drop regulator that supplies the logic can be adjusted according to the system's maximum operating frequency and the external voltage supply:

- In Range 1 (V_{DD} range limited to 1.71-3.6 V), the CPU runs at up to 32 MHz (refer to *Table 17* for consumption).
- In Range 2 (full V_{DD} range), the CPU runs at up to 16 MHz (refer to *Table 17* for consumption)
- In Range 3 (full V_{DD} range), the CPU runs at up to 4 MHz (generated only with the multispeed internal RC oscillator clock source). Refer to *Table 17* for consumption.

Seven low power modes are provided to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

- **Sleep** mode

  In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

  Sleep mode power consumption: refer to *Table 19*.

- **Low power run** mode

  This mode is achieved with the multispeed internal (MSI) RC oscillator set to the minimum clock (65 kHz), execution from SRAM or Flash memory, and internal regulator in low power mode to minimize the regulator's operating current. In the Low power run mode, the clock frequency and the number of enabled peripherals are both limited.

  Low power run mode consumption: refer to *Table 20: Current consumption in Low power run mode*.

- **Low power sleep** mode

  This mode is achieved by entering the Sleep mode with the internal voltage regulator in Low power mode to minimize the regulator's operating current. In the Low power sleep mode, both the clock frequency and the number of enabled peripherals are limited; a typical example would be to have a timer running at 32 kHz.
  When wakeup is triggered by an event or an interrupt, the system reverts to the run mode with the regulator on.

  Low power sleep mode consumption: refer to *Table 21: Current consumption in Low power sleep mode*.

- **Stop** mode with RTC

  Stop mode achieves the lowest power consumption while retaining the RAM and register contents and real time clock. All clocks in the V_{CORE} domain are stopped, the PLL, MSI RC, HSI RC and HSE crystal oscillators are disabled. The LSE or LSI is still running. The voltage regulator is in the low power mode.

  The device can be woken up from Stop mode by any of the EXTI line, in 8 µs. The EXTI line source can be one of the 16 external lines. It can be the PVD output, the Comparator 1 event or Comparator 2 event (if internal reference voltage is on), it can be the RTC alarm(s), the USB wakeup, the RTC tamper events, the RTC timestamp event or the RTC wakeup.

- **Stop** mode without RTC

  Stop mode achieves the lowest power consumption while retaining the RAM and register contents. All clocks are stopped, the PLL, MSI RC, HSI and LSI RC, LSE and

Nested vectored interrupt controller (NVIC)

The ultra-low-power STM32L151x6/8/B and STM32L152x6/8/B devices embed a nested vectored interrupt controller able to handle up to 45 maskable interrupt channels (not including the 16 interrupt lines of Cortex®-M3) and 16 priority levels.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of *late arriving*, higher-priority interrupts
- Support for tail-chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimal interrupt latency.

3.3 Reset and supply management

3.3.1 Power supply schemes

- V_{DD} = 1.65 to 3.6 V: external power supply for I/Os and the internal regulator. Provided externally through V_{DD} pins.
- V_{SSA}, V_{DDA} = 1.65 to 3.6 V: external analog power supplies for ADC, reset blocks, RCs and PLL (minimum voltage to be applied to V_{DDA} is 1.8 V when the ADC is used). V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS}, respectively.

3.3.2 Power supply supervisor

The device has an integrated ZEROPOWER power-on reset (POR)/power-down reset (PDR) that can be coupled with a brownout reset (BOR) circuitry.

The device exists in two versions:

- The version with BOR activated at power-on operates between 1.8 V and 3.6 V.
- The other version without BOR operates between 1.65 V and 3.6 V.

After the V_{DD} threshold is reached (1.65 V or 1.8 V depending on the BOR which is active or not at power-on), the option byte loading process starts, either to confirm or modify default thresholds, or to disable the BOR permanently: in this case, the V_{DD} min value becomes 1.65 V (whatever the version, BOR active or not, at power-on).

When BOR is active at power-on, it ensures proper operation starting from 1.8 V whatever the power ramp-up phase before it reaches 1.8 V. When BOR is not active at power-up, the power ramp-up should guarantee that 1.65 V is reached on V_{DD} at least 1 ms after it exits the POR area.

3.5 Low power real-time clock and backup registers

The real-time clock (RTC) is an independent BCD timer/counter. Dedicated registers contain the second, minute, hour (12/24 hour), week day, date, month, year, in BCD (binary-coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day of the month are made automatically. The RTC provides a programmable alarm and programmable periodic interrupts with wakeup from Stop and Standby modes.

- The programmable wakeup time ranges from 120 µs to 36 hours
- Stop mode consumption with LSI and Auto-wakeup: 1.2 µA (at 1.8 V) and 1.4 µA (at 3.0 V)
- Stop mode consumption with LSE, calendar and Auto-wakeup: 1.3 µA (at 1.8V), 1.6 µA (at 3.0 V)

The RTC can be calibrated with an external 512 Hz output, and a digital compensation circuit helps reduce drift due to crystal deviation.

There are twenty 32-bit backup registers provided to store 80 bytes of user application data. They are cleared in case of tamper detection.

3.6 GPIOs (general-purpose inputs/outputs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions, and can be individually remapped using dedicated AFIO registers. All GPIOs are high current capable. The alternate function configuration of I/Os can be locked if needed following a specific sequence in order to avoid spurious writing to the I/O registers. The I/O controller is connected to the AHB with a toggling speed of up to 16 MHz.

External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 23 edge detector lines used to generate interrupt/event requests. Each line can be individually configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 83 GPIOs can be connected to the 16 external interrupt lines. The 7 other lines are connected to RTC, PVD, USB or Comparator events.

3.10 ADC (analog-to-digital converter)

A 12-bit analog-to-digital converters is embedded into STM32L151x6/8/B and STM32L152x6/8/B devices with up to 24 external channels, performing conversions in single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC can be served by the DMA controller.

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the general-purpose timers (TIMx) can be internally connected to the ADC start trigger and injection trigger, to allow the application to synchronize A/D conversions and timers. An injection mode allows high priority conversions to be done by interrupting a scan mode which runs in as a background task.

The ADC includes a specific low power mode. The converter is able to operate at maximum speed even if the CPU is operating at a very low frequency and has an auto-shutdown function. The ADC's runtime and analog front-end current consumption are thus minimized whatever the MCU operating mode.

3.10.1 Temperature sensor

The temperature sensor (TS) generates a voltage V_{SENSE} that varies linearly with temperature.

The temperature sensor is internally connected to the ADC_IN16 input channel which is used to convert the sensor output voltage into a digital value.

The sensor provides good linearity but it has to be calibrated to obtain good overall accuracy of the temperature measurement. As the offset of the temperature sensor varies from chip to chip due to process variation, the uncalibrated internal temperature sensor is suitable for applications that detect temperature changes only.

To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by ST in the system memory area, accessible in read-only mode, see *Table 58: Temperature sensor calibration values*.

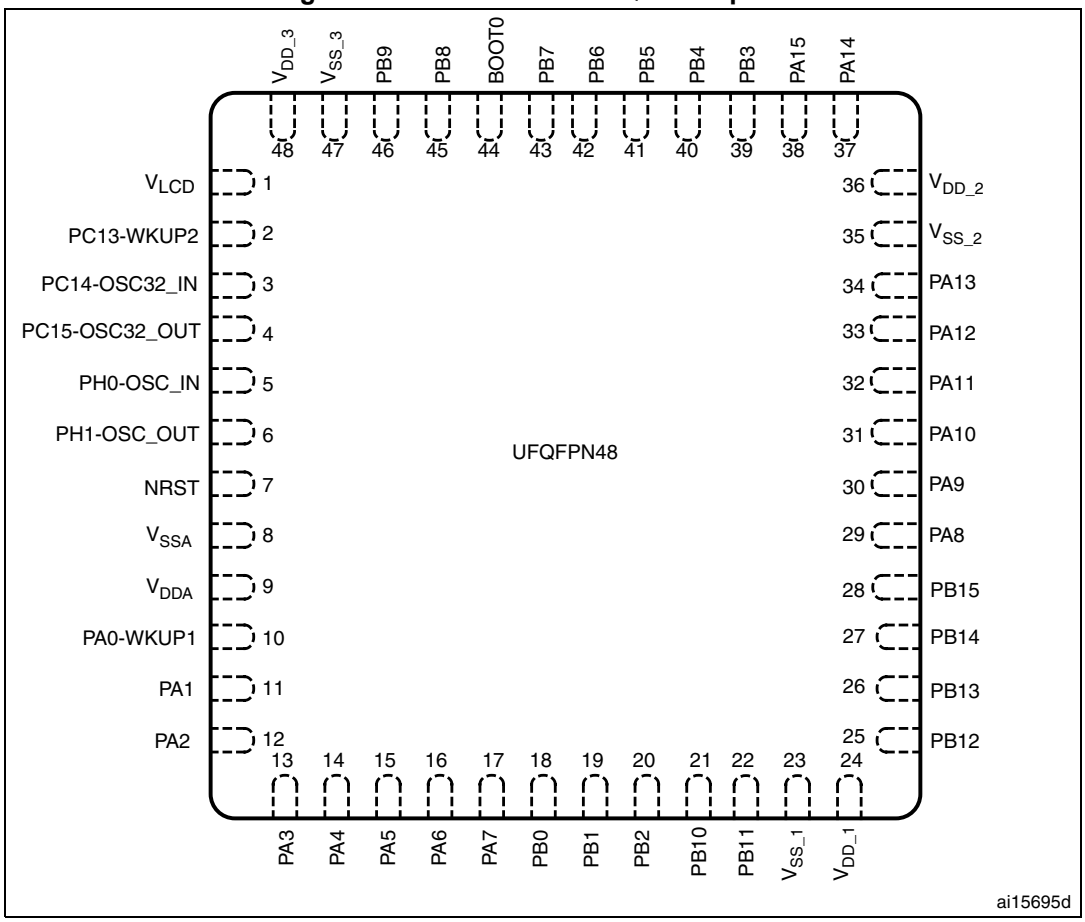
3.10.2 Internal voltage reference (V_{REFINT})

The internal voltage reference (V_{REFINT}) provides a stable (bandgap) voltage output for the ADC and Comparators. V_{REFINT} is internally connected to the ADC_IN17 input channel. It enables accurate monitoring of the V_{DD} value (when no external voltage, VREF+, is available for ADC). The precise voltage of V_{REFINT} is individually measured for each part by ST during production test and stored in the system memory area. It is accessible in read-only mode see *Table 16: Embedded internal reference voltage*.

3.11 DAC (digital-to-analog converter)

The two 12-bit buffered DAC channels can be used to convert two digital signals into two analog voltage signal outputs. The chosen design structure is composed of integrated resistor strings and an amplifier in non-inverting configuration.

Figure 8. STM32L15xCx UFQFPN48 pinout



1. This figure shows the package top view.

Table 8. STM32L151x6/8/B and STM32L152x6/8/B pin definitions (continued)

Pins					Pin name	Pin type[1]	I/O structure	Main function[2] (after reset)	Pins functions	
LQFP100	LQFP64	TFBGA64	UFBGA100	LQFP48 or UFQFPN48					Alternate functions	Additional functions
19	12	F1	J1	8	V_{SSA}	S	-	V_{SSA}	-	-
20	-	-	K1	-	V_{REF-}	S	-	V_{REF-}	-	-
21	-	G1 (6)	L1	-	V_{REF+}	S	-	V_{REF+}	-	-
22	13	H1	M1	9	V_{DDA}	S	-	V_{DDA}	-	-
23	14	G2	L2	10	PA0-WKUP1	I/O	FT	PA0	USART2_CTS/ TIM2_CH1_ETR	WKUP1/ ADC_IN0/ COMP1_INP
24	15	H2	M2	11	PA1	I/O	FT	PA1	USART2_RTS/ TIM2_CH2/LCD_SEG0	ADC_IN1/ COMP1_INP
25	16	F3	K3	12	PA2	I/O	FT	PA2	USART2_TX/TIM2_CH3/ TIM9_CH1/LCD_SEG1	ADC_IN2/ COMP1_INP
26	17	G3	L3	13	PA3	I/O	TC	PA3	USART2_RX/TIM2_CH4/ TIM9_CH2/LCD_SEG2	ADC_IN3/ COMP1_INP
27	18	C2	E3	-	V_{SS_4}	S	-	V_{SS_4}	-	-
28	19	D2	H3	-	V_{DD_4}	S	-	V_{DD_4}	-	-
29	20	H3	M3	14	PA4	I/O	TC	PA4	SPI1_NSS/USART2_CK	ADC_IN4/ DAC_OUT1/ COMP1_INP
30	21	F4	K4	15	PA5	I/O	TC	PA5	SPI1_SCK/ TIM2_CH1_ETR	ADC_IN5/ DAC_OUT2/ COMP1_INP
31	22	G4	L4	16	PA6	I/O	FT	PA6	SPI1_MISO/TIM3_CH1/ LCD_SEG3/TIM10_CH1	ADC_IN6 /COMP1_INP
32	23	H4	M4	17	PA7	I/O	FT	PA7	SPI1_MOSI//TIM3_CH2/ LCD_SEG4/TIM11_CH1	ADC_IN7/ COMP1_INP
33	24	H5	K5	-	PC4	I/O	FT	PC4	LCD_SEG22	ADC_IN14/ COMP1_INP
34	25	H6	L5	-	PC5	I/O	FT	PC5	LCD_SEG23	ADC_IN15/ COMP1_INP

Table 9. Alternate function input/output (continued)

Port name	Digital alternate function number														
	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFOI6	AFIO7	AFIO8	AFIO9	AFIO11	AFIO12	AFIO13	AFIO14	AFIO15
	Alternate function														
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PB5	-	-	TIM3_CH2	-	I2C1_ SMBA	SPI1_MOSI	-	-	-	-	[SEG9]	-	-	-	EVENTOUT
PB6	-	-	TIM4_CH1	-	I2C1_SCL	-	-	USART1_TX	-	-	-	-	-	-	EVENTOUT
PB7	-	-	TIM4_CH2	-	I2C1_SDA	-	-	USART1_RX	-	-	-	-	-	-	EVENTOUT
PB8	-	-	TIM4_CH3	TIM10_CH1*	I2C1_SCL	-	-	-	-	-	SEG16	-	-	-	EVENTOUT
PB9	-	-	TIM4_CH4	TIM11_CH1*	I2C1_SDA	-	-	-	-	-	[COM3]	-	-	-	EVENTOUT
PB10	-	TIM2_CH3	-	-	I2C2_SCL	-	-	USART3_TX	-	-	SEG10	-	-	-	EVENTOUT
PB11	-	TIM2_CH4	-	-	I2C2_SDA	-	-	USART3_RX	-	-	SEG11	-	-	-	EVENTOUT
PB12	-	-	-	TIM10_CH1	I2C2_ SMBA	SPI2_NSS	-	USART3_CK	-	-	SEG12	-	-	-	EVENTOUT
PB13	-	-	-	TIM9_CH1	-	SPI2_SCK	-	USART3_CTS	-	-	SEG13	-	-	-	EVENTOUT
PB14	-	-	-	TIM9_CH2	-	SPI2_MISO	-	USART3_RTS	-	-	SEG14	-	-	-	EVENTOUT
PB15	-	-	-	TIM11_CH1	-	SPI2_MOSI	-	-	-	-	SEG15	-	-	-	EVENTOUT
PC0	-	-	-	-	-	-	-	-	-	-	SEG18	-	-	TIMx_IC1	EVENTOUT
PC1	-	-	-	-	-	-	-	-	-	-	SEG19	-	-	TIMx_IC2	EVENTOUT
PC2	-	-	-	-	-	-	-	-	-	-	SEG20	-	-	TIMx_IC3	EVENTOUT
PC3	-	-	-	-	-	-	-	-	-	-	SEG21	-	-	TIMx_IC4	EVENTOUT
PC4	-	-	-	-	-	-	-	-	-	-	SEG22	-	-	TIMx_IC1	EVENTOUT
PC5	-	-	-	-	-	-	-	-	-	-	SEG23	-	-	TIMx_IC2	EVENTOUT
PC6	-	-	TIM3_CH1	-	-	-	-	-	-	-	SEG24	-	-	TIMx_IC3	EVENTOUT
PC7	-	-	TIM3_CH2	-	-	-	-	-	-	-	SEG25	-	-	TIMx_IC4	EVENTOUT
PC8	-	-	TIM3_CH3	-	-	-	-	-	-	-	SEG26	-	-	TIMx_IC1	EVENTOUT
PC9	-	-	TIM3_CH4	-	-	-	-	-	-	-	SEG27	-	-	TIMx_IC2	EVENTOUT
PC10	-	-	-	-	-	-	-	USART3_TX	-	-	COM4 / SEG28 / SEG40	-	-	TIMx_IC3	EVENTOUT

Table 9. Alternate function input/output (continued)

Port name	Digital alternate function number														
	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFOI6	AFIO7	AFIO8	AFIO9	AFIO11	AFIO12	AFIO13	AFIO14	AFIO15
	Alternate function														
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PC11	-	-	-	-	-	-	-	USART3_RX	-	-	COM5 / SEG29 / SEG41	-	-	TIMx_IC4	EVENTOUT
PC12	-	-	-	-	-	-	-	USART3_CK	-	-	COM6 / SEG30 / SEG42	-	-	TIMx_IC1	EVENTOUT
PC13-WKUP2	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PC14-OSC32_IN	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PC15-OSC32_OUT	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PD0	-	-	-	TIM9_CH1	-	SPI2_NSS	-	-	-	-	-	-	-	TIMx_IC1	EVENTOUT
PD1	-	-	-	-	-	SPI2_SCK	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PD2	-	-	TIM3_ETR	-	-	-	-	-	-	-	COM7 / SEG31 / SEG43	-	-	TIMx_IC3	EVENTOUT
PD3	-	-	-	-	-	SPI2_MISO	-	USART2_CTS	-	-	-	-	-	TIMx_IC4	EVENTOUT
PD4	-	-	-	-	-	SPI2_MOSI	-	USART2_RTS	-	-	-	-	-	TIMx_IC1	EVENTOUT
PD5	-	-	-	-	-	-	-	USART2_TX	-	-	-	-	-	TIMx_IC2	EVENTOUT
PD6	-	-	-	-	-	-	-	USART2_RX	-	-	-	-	-	TIMx_IC3	EVENTOUT
PD7	-	-	-	TIM9_CH2	-	-	-	USART2_CK	-	-	-	-	-	TIMx_IC4	EVENTOUT
PD8	-	-	-	-	-	-	-	USART3_TX	-	-	-	-	-	TIMx_IC1	EVENTOUT
PD9	-	-	-	-	-	-	-	USART3_RX	-	-	-	-	-	TIMx_IC2	EVENTOUT
PD10	-	-	-	-	-	-	-	USART3_CK	-	-	-	-	-	TIMx_IC3	EVENTOUT
PD11	-	-	-	-	-	-	-	USART3_CTS	-	-	-	-	-	TIMx_IC4	EVENTOUT
PD12	-	-	TIM4_CH1	-	-	-	-	USART3_RTS	-	-	-	-	-	TIMx_IC1	EVENTOUT

Table 18. Current consumption in Run mode, code with data processing running from RAM

Symbol	Parameter	Conditions		f_{HCLK}	Typ	Max(1)			Unit
						55 °C	85 °C	105 °C	
I_{DD} (Run from RAM)	Supply current in Run mode, code executed from RAM, Flash switched off	$f_{HSE} = f_{HCLK}$ up to 16 MHz, included $f_{HSE} = f_{HCLK}/2$ above 16 MHz (PLL ON)(2)	Range 3, V_{CORE}=1.2 V VOS[1:0] = 11	1 MHz	200	300	300	300	µA
				2 MHz	380	500	500	500	
				4 MHz	720	860	860	860(3)	
			Range 2, V_{CORE}=1.5 V VOS[1:0] = 10	4 MHz	0.9	1	1	1	mA
				8 MHz	1.65	2	2	2	
				16 MHz	3.2	3.7	3.7	3.7	
			Range 1, V_{CORE}=1.8 V VOS[1:0] = 01	8 MHz	2	2.5	2.5	2.5	
				16 MHz	4	4.5	4.5	4.5	
				32 MHz	7.7	8.5	8.5	8.5	
		HSI clock source (16 MHz)	Range 2, V_{CORE}=1.5 V VOS[1:0] = 10	16 MHz	3.3	3.8	3.8	3.8	
			Range 1, V_{CORE}=1.8 V VOS[1:0] = 01	32 MHz	7.8	9.2	9.2	9.2	
		MSI clock, 65 kHz	Range 3, V_{CORE}=1.2 V VOS[1:0] = 11	65 kHz	40	60	60	80	µA
		MSI clock, 524 kHz		524 kHz	110	140	140	160	
		MSI clock, 4.2 MHz		4.2 MHz	700	800	800	820	

1. Guaranteed by characterization results, unless otherwise specified.
2. Oscillator bypassed (HSEBYP = 1 in RCC_CR register).
3. Tested in production.

Table 19. Current consumption in Sleep mode

Symbol	Parameter	Conditions		f_{HCLK}	Typ	Max(1)			Unit
						55 °C	85 °C	105 °C	
I_{DD} (Sleep)	Supply current in Sleep mode, code executed from RAM, Flash switched OFF	f_{HSE} = f_{HCLK} up to 16 MHz included, f_{HSE} = f_{HCLK}/2 above 16 MHz (PLL ON)(2)	Range 3, V_{CORE}=1.2 V VOS[1:0] = 11	1 MHz	80	140	140	140	µA
				2 MHz	150	210	210	210	
				4 MHz	280	330	330	330(3)	
			Range 2, V_{CORE}=1.5 V VOS[1:0] = 10	4 MHz	280	400	400	400	
				8 MHz	450	550	550	550	
				16 MHz	900	1050	1050	1050	
			Range 1, V_{CORE}=1.8 V VOS[1:0] = 01	8 MHz	550	650	650	650	
				16 MHz	1050	1200	1200	1200	
				32 MHz	2300	2500	2500	2500	
		HSI clock source (16 MHz)	Range 2, V_{CORE}=1.5 V VOS[1:0] = 10	16 MHz	1000	1100	1100	1100	
			Range 1, V_{CORE}=1.8 V VOS[1:0] = 01	32 MHz	2300	2500	2500	2500	
		MSI clock, 65 kHz	Range 3, V_{CORE}=1.2 V VOS[1:0] = 11	65 kHz	30	50	50	60	
		MSI clock, 524 kHz		524 kHz	50	70	70	80	
		MSI clock, 4.2 MHz		4.2 MHz	200	240	240	250	
	Supply current in Sleep mode, code executed from Flash	f_{HSE} = f_{HCLK} up to 16 MHz included, f_{HSE} = f_{HCLK}/2 above 16 MHz (PLL ON)(2)	Range 3, V_{CORE}=1.2 V VOS[1:0] = 11	1 MHz	80	140	140	140	µA
				2 MHz	150	210	210	210	
				4 MHz	290	350	350	350	
			Range 2, V_{CORE}=1.5 V VOS[1:0] = 10	4 MHz	300	400	400	400	
				8 MHz	500	600	600	600	
				16 MHz	1000	1100	1100	1100	
			Range 1, V_{CORE}=1.8 V VOS[1:0] = 01	8 MHz	550	650	650	650	
				16 MHz	1050	1200	1200	1200	
				32 MHz	2300	2500	2500	2500	
		HSI clock source (16 MHz)	Range 2, V_{CORE}=1.5 V VOS[1:0] = 10	16 MHz	1000	1100	1100	1100	
			Range 1, V_{CORE}=1.8 V VOS[1:0] = 01	32 MHz	2300	2500	2500	2500	

Table 22. Typical and maximum current consumptions in Stop mode

Symbol	Parameter	Conditions			Typ (1)	Max (1)(2)	Unit
I_{DD} (Stop with RTC)	Supply current in Stop mode with RTC enabled	RTC clocked by LSI, regulator in LP mode, HSI and HSE OFF (no independent watchdog)	LCD OFF	T_A = -40°C to 25°C V_{DD} = 1.8 V	1.2	2.75	µA
				T_A = -40°C to 25°C	1.4	4	
				T_A = 55°C	2.6	6	
				T_A= 85°C	4.8	10	
				T_A = 105°C	10.2	23	
			LCD ON (static duty)(3)	T_A = -40°C to 25°C	3.3	6	
				T_A = 55°C	4.5	8	
				T_A= 85°C	6.6	12	
				T_A = 105°C	13.6	27	
			LCD ON (1/8 duty)(4)	T_A = -40°C to 25°C	7.7	10	
				T_A = 55°C	8.6	12	
				T_A= 85°C	10.7	16	
				T_A = 105°C	19.8	40	
		RTC clocked by LSE external clock (32.768 kHz), regulator in LP mode, HSI and HSE OFF (no independent watchdog)	LCD OFF	T_A = -40°C to 25°C	1.6	4	
				T_A = 55°C	2.7	6	
				T_A= 85°C	4.8	10	
				T_A = 105°C	10.3	23	
			LCD ON (static duty)(3)	T_A = -40°C to 25°C	3.6	6	
				T_A = 55°C	4.6	8	
				T_A= 85°C	6.7	12	
				T_A = 105°C	10.9	23	
			LCD ON (1/8 duty)(4)	T_A = -40°C to 25°C	7.6	10	
				T_A = 55°C	8.6	12	
				T_A= 85°C	10.7	16	
				T_A = 105°C	19.8	40	
		RTC clocked by LSE (no independent watchdog)(5)	LCD OFF	T_A = -40°C to 25°C V_{DD} = 1.8 V	1.45	-	
				T_A = -40°C to 25°C V_{DD} = 3.0 V	1.9	-	
				T_A = -40°C to 25°C V_{DD} = 3.6 V	2.2	-	

Table 24. Peripheral current consumption(1)

Peripheral		Typical consumption, V_{DD} = 3.0 V, T_A = 25 °C				Unit
		Range 1, V_{CORE}=1.8 V VOS[1:0] = 01	Range 2, V_{CORE}=1.5 V VOS[1:0] = 10	Range 3, V_{CORE}=1.2 V VOS[1:0] = 11	Low power sleep and run	
APB1	TIM2	13	10.5	8	10.5	µA/MHz (f_{HCLK})
	TIM3	14	12	9	12	
	TIM4	12.5	10.5	8	11	
	TIM6	5.5	4.5	3.5	4.5	
	TIM7	5.5	5	3.5	4.5	
	LCD	5.5	5	3.5	5	
	WWDG	4	3.5	2.5	3.5	
	SPI2	5.5	5	4	5	
	USART2	9	8	5.5	8.5	
	USART3	10.5	9	6	8	
	I2C1	8.5	7	5.5	7.5	
	I2C2	8.5	7	5.5	6.5	
	USB	12.5	10	6.5	10	
	PWR	4.5	4	3	3.5	
	DAC	9	7.5	6	7	
	COMP	4.5	4	3.5	4.5	
APB2	SYSCFG & RI	3	2.5	2	2.5	µA/MHz (f_{HCLK})
	TIM9	9	7.5	6	7	
	TIM10	6.5	5.5	4.5	5.5	
	TIM11	7	6	4.5	5.5	
	ADC(2)	11.5	9.5	8	9	
	SPI1	5	4.5	3	4	
	USART1	9	7.5	6	7.5	

Figure 22. SPI timing diagram - slave mode and CPHA = 0

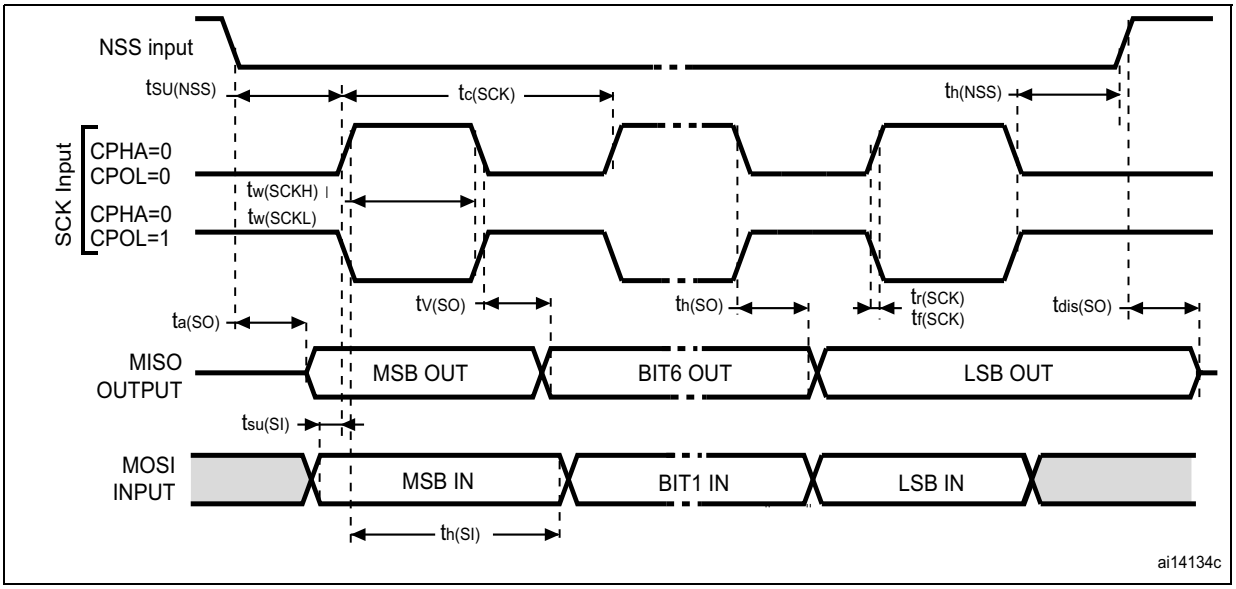
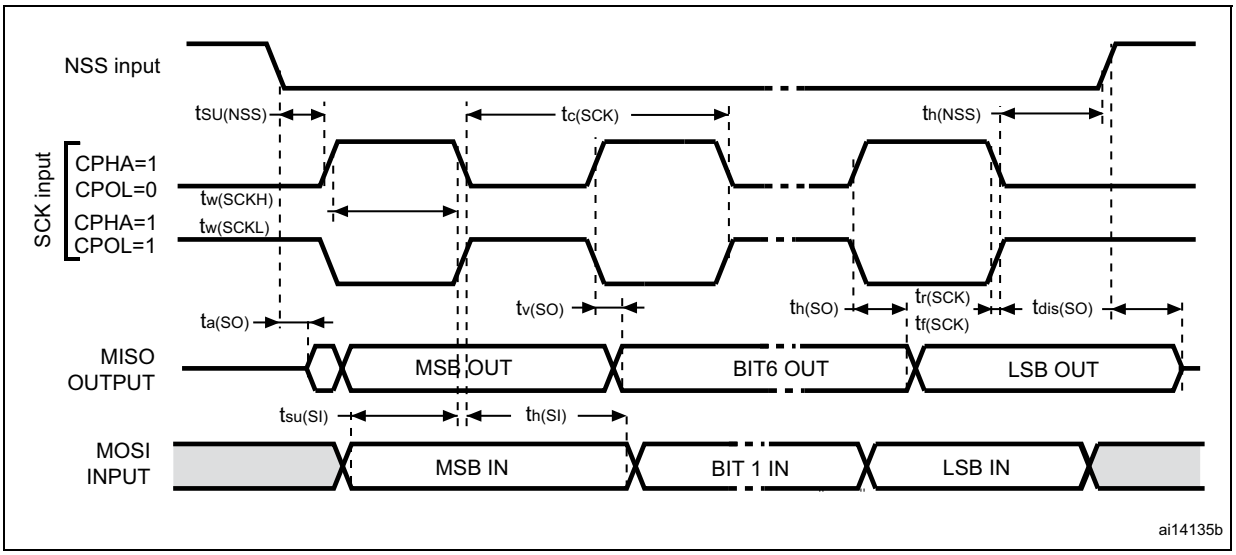


Figure 23. SPI timing diagram - slave mode and CPHA = 1(1)



1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

Table 61. Comparator 2 characteristics

Symbol	Parameter	Conditions	Min	Typ	Max(1)	Unit
V_{DDA}	Analog supply voltage	-	1.	-	3.6	V
V_{IN}	Comparator 2 input voltage range	-	0	-	V_{DDA}	V
t_{START}	Comparator startup time	Fast mode	-	15	20	µs
		Slow mode	-	20	25	
$t_{d\ slow}$	Propagation delay(2) in slow mode	1. V ≤V_{DDA} ≤2.7 V	-	1.8	3.5	
		2.7 V ≤V_{DDA} ≤3.6 V	-	2.5	6	
$t_{d\ fast}$	Propagation delay(2) in fast mode	1. V ≤V_{DDA} ≤2.7 V	-	0.8	2	
		2.7 V ≤V_{DDA} ≤3.6 V	-	1.2	4	
V_{offset}	Comparator offset error	-	-	±4	±20	mV
dThreshold/ dt	Threshold voltage temperature coefficient	V_{DDA} = 3.3V T_A = 0 to 50 °C V- = V_{REFINT}, 3/4 V_{REFINT}, 1/2 V_{REFINT}, 1/4 V_{REFINT}	-	15	100	ppm /°C
I_{COMP2}	Current consumption(3)	Fast mode	-	3.5	5	µA
		Slow mode	-	0.5	2	

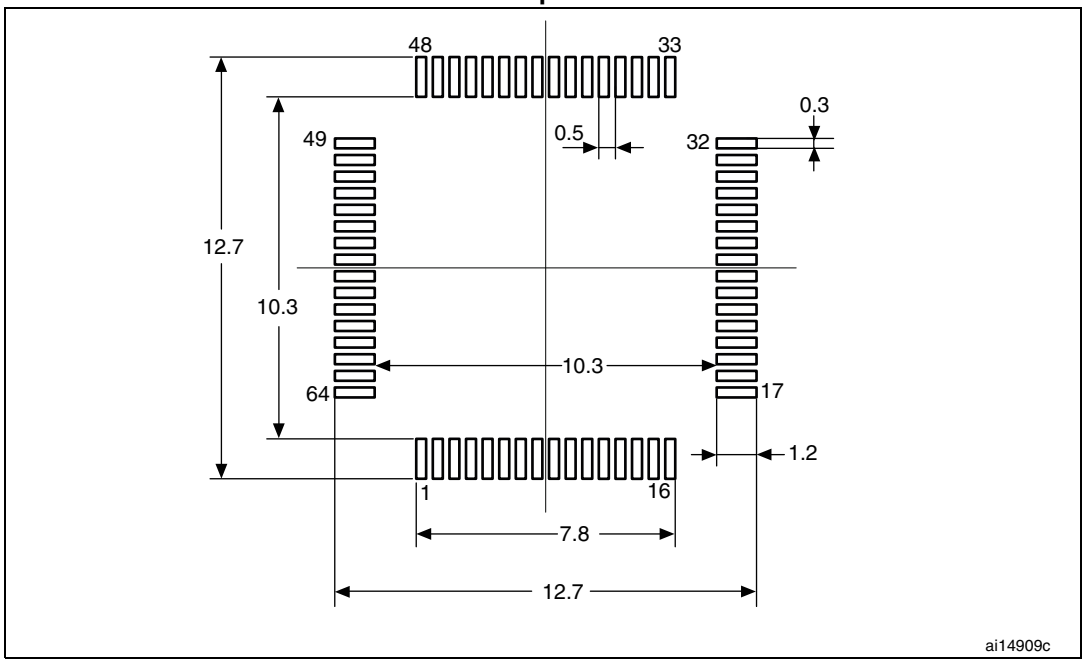
1. Guaranteed by characterization results.
2. The delay is characterized for 100 mV input step with 10 mV overdrive on the inverting input, the non-inverting input set to the reference.
3. Comparator consumption only. Internal reference voltage (necessary for comparator operation) is not included.

Table 64. LQFP64 10 x 10 mm, 64-pin low-profile quad flat package mechanical data (continued)

Symbol	millimeters			inches[1]		
	Min	Typ	Max	Typ	Min	Max
E3	-	7.500	-	-	0.2953	-
e	-	0.500	-	-	0.0197	-
K	0°	3.5°	7°	0°	3.5°	7°
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 36. LQFP64 10 x 10 mm, 64-pin low-profile quad flat package recommended footprint

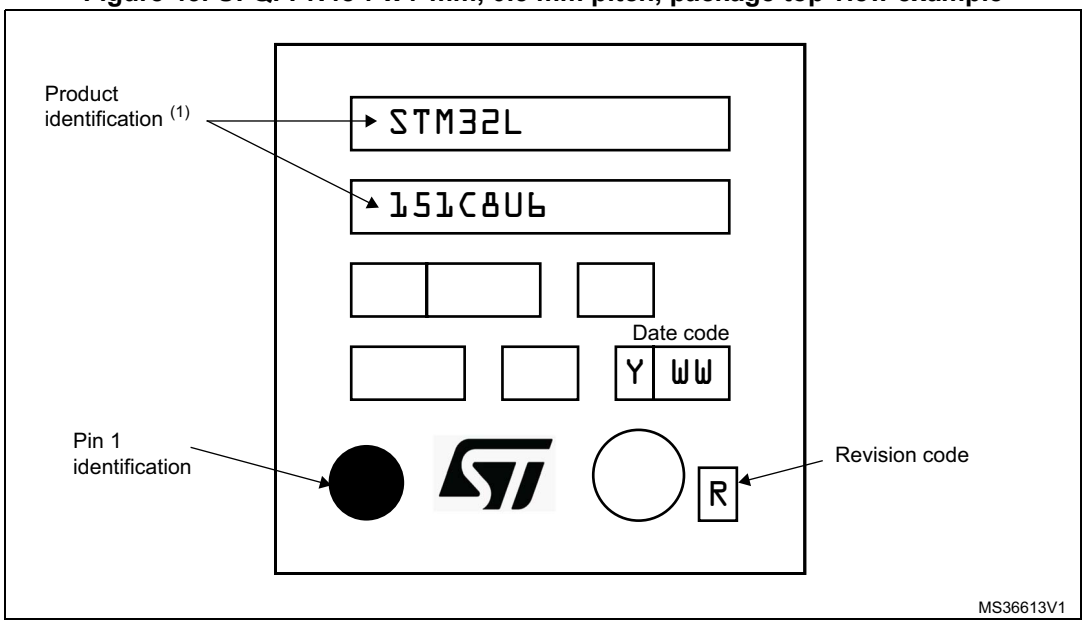


1. Dimensions are in millimeters.

UFQFPN48 device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Figure 43. UFQFPN48 7 x 7 mm, 0.5 mm pitch, package top view example

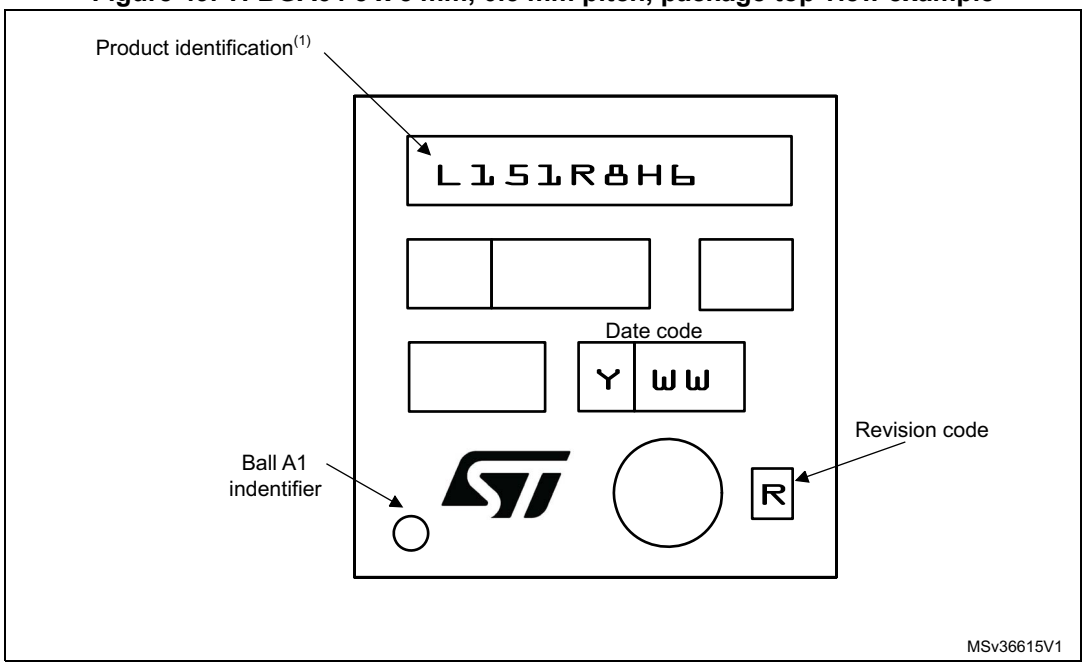


1. Parts marked as “ES”, “E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

TFBGA64 device marking

The following figure gives an example of topside marking orientation versus ball A1 identifier location.

Figure 49. TFBGA64 5 x 5 mm, 0.5 mm pitch, package top view example



1. Parts marked as “ES”, “E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

9 Revision history

Table 73. Document revision history

Date	Revision	Changes
02-Jul-2010	1	Initial release.
01-Oct-2010	2	Removed 5 V tolerance (FT) from PA3, PB0 and PC3 in *Table 8: STM32L15xx6/8/B pin definitions* Updated *Table 14: Embedded reset and power control block characteristics* Updated *Table 16: Embedded internal reference voltage* Added *Table 53: ADC clock frequency* Updated *Table 54: ADC characteristics*
16-Dec-2010	3	Modified consumptions on page 1 and in *Section 3.1: Low power modes* LED_SEG8 removed on PB6. Updated *Section 6: Electrical characteristics* VFQFPN48 replaced by UFQFPN48
25-Feb-2011	4	*Section 3.3.2: Power supply supervisor*: updated note. *Table 8: STM32L15xx6/8/B pin definitions:* modified main function (after reset) and alternate function for OSC_IN and OSC_OUT pins; modified footnote 5; added footnote to OSC32_IN and OSC32_OUT pins; C1 and D1 removed on PD0 and PD1 pins (TFBGA64 column). *Section 3.11: DAC (digital-to-analog converter)*: updated bullet list. *Table 10: Voltage characteristics on page 52*: updated footnote 3 regarding $I_{INJ(PIN)}$. *Table 11: Current characteristics on page 52*: updated footnote 4 regarding positive and negative injection. *Table 14: Embedded reset and power control block characteristics on page 54*: updated typ and max values for $T_{RSTTEMPO}$ (V_{DD} rising, BOR enabled). *Table 17: Current consumption in Run mode, code with data processing running from Flash on page 58*: removed values for HSI clock source (16 MHz), Range 3. *Table 18: Current consumption in Run mode, code with data processing running from RAM on page 59*: removed values for HSI clock source (16 MHz), Range 3. *Table 19: Current consumption in Sleep mode on page 60* removed values for HSI clock source (16 MHz), Range 3 for both RAM and Flash; changed units. *Table 20: Current consumption in Low power run mode on page 62*: updated parameter and max value of I_{DD} Max (LP Run). *Table 21: Current consumption in Low power sleep mode on page 63*: updated symbol, parameter, and max value of I_{DD} Max (LP Sleep). *Table 22: Typical and maximum current consumptions in Stop mode on page 64* updated values for $I_{DD\ (Stop\ with\ RTC)}$ - RTC clocked by LSE external clock (32.768 kHz), regulator in LP mode, HSI and HSE OFF (no independent watchdog).

Table 73. Document revision history (continued)

Date	Revision	Changes
17-June-2011	5	Modified 1st page (low power features) Added STM32L15xC6 and STM32L15xR6 devices (32 Kbytes of Flash memory). Modified *Section 3.6: GPIOs (general-purpose inputs/outputs) on page 22* Modified *Section 6.3: Operating conditions on page 53* Modified *Table 55: ADC accuracy on page 95*, *Table 57: DAC characteristics on page 99* and *Table 60: Comparator 1 characteristics on page 102*
25-Jan-2012	6	*Features*: updated internal multispeed low power RC. *Table 2: Ultralow power STM32L15xx6/8/B device features and peripheral counts*: LCD 4x44 and 8x40 available for both 64- and 128-Kbyte devices; two comparators available for all devices. *Table 3: Functionalities depending on the operating power supply range*: added footnote *1*. *Figure 8: STM32L15xCx UFQFPN48 pinout*: replaced VFQPN48 by UFQFPN48 as name of package. *Table 8: STM32L15xx6/8/B pin definitions*: replaced PH0/PH1 by PC14/PC15. *Table 9: Alternate function input/output*: removed EVENT OUT from PH2 port, AFIO15 column. *Table 19: Current consumption in Sleep mode*: updated MSI conditions and f_{HCLK}. *Table 20: Current consumption in Low power run mode*: updated some temperature conditions; added footnote *2.* *Table 21: Current consumption in Low power sleep mode*: updated some temperature conditions and one of the MSI clock conditions. *Table 22: Typical and maximum current consumptions in Stop mode*: updated I_{DD} (WU from Stop) parameter. *Table 23: Typical and maximum current consumptions in Standby mode*: updated I_{DD} (WU from Standby) parameter. *Table 25: Low-power mode wakeup timings*: updated f_{HCLK} value for $t_{WUSLEEP\_LP}$; updated typical value of parameter “Wakeup from Stop mode, regulator in Run mode”. *Table 24: Peripheral current consumption*: replaced GPIOF by GPIOH. *Table 33: PLL characteristics*: updated “PLL output clock” *Table 35: Flash memory and data EEPROM characteristics*: updated all information for I_{DD}. *Figure 19: I/O AC characteristics definition*: replaced the falling edge “$t_{r(IO)out}$” by “$t_{f(IO)out}$”. *Table 47: I2C characteristics*: amended footnote *2.* *Table 54: ADC characteristics*: updated f_S max value for direct channels, 6-bit sampling rate. *Table 55: ADC accuracy*: Updated the first, third and fourth f_{ADC} test condition. *Table 59: Temperature sensor characteristics*: updated typ, min, and max values of the T_{S_temp} parameter.